

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

July 2014



FCH130N60 N-Channel SuperFET[®] II MOSFET 600 V, 28 A, 130 mΩ

Features

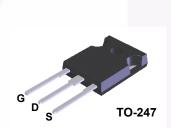
- 650 V @ T_J = 150°C
- Typ. R_{DS(on)} = 112 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 54 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 240 pF)
- 100% Avalanche Tested
- RoHS Compliant

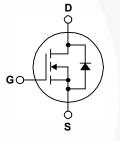
Applications

- Telecom / Sever Power Supplies
- Industrial Power Supplies
- AC-DC Power Supply

Description

SuperFET[®] II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This advanced technology is tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is suitable for various AC/DC power conversion for system miniaturization and higher efficiency.





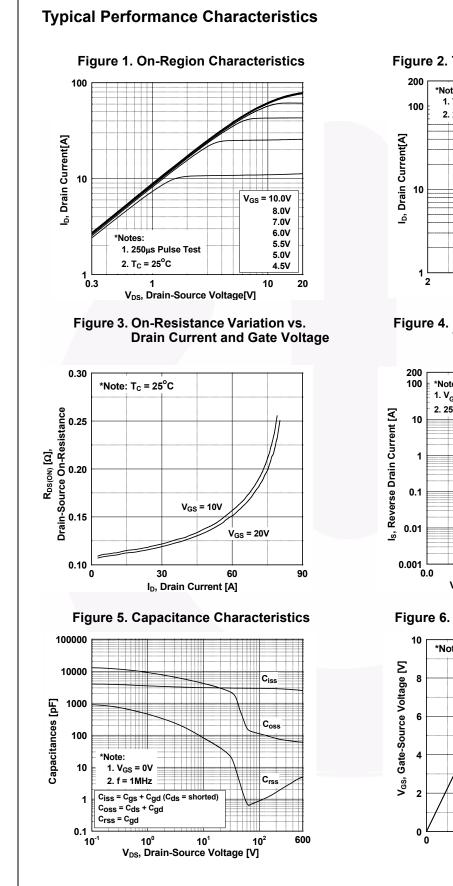
Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FCH130N60	Unit		
V _{DSS}	Drain to Source Voltage		600	V		
V _{GSS}	Cata ta Sauraa Maltaga	- DC	- DC		V	
	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	v	
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		28	А	
		- Continuous (T _C = 100 ^o C)		18	A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	84	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		720	mJ		
I _{AR}	Avalanche Current (Note 1)		6	Α		
E _{AR}	Repetitive Avalanche Energy (Note 1)		2.78	mJ		
dv/dt	MOSFET dv/dt			100	V/ns	
	Peak Diode Recovery dv/dt (Note 3)			20		
P _D	Dawar Dissingtion	(T _C = 25 ^o C)		278	W	
	Power Dissipation	- Derate Above 25°C		2.2	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		econds	300	°C	

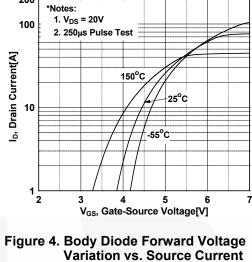
Thermal Characteristics

Symbol	Parameter	FCH130N60	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.45	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.	40	- °C/W

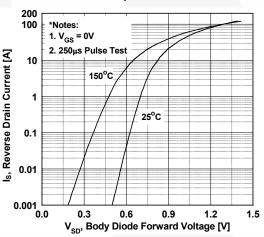
		Top Mark	Package	Packing Method	Reel Size	Тар	e Width	Quantity	
		FCH130N60	TO-247	Tube	N/A	N/A		30 units	
Electrica	I Chara	acteristics T _c =	= 25°C unless	otherwise noted					
Symbol		Parameter	20 0 011000	Test Cond	ditions	Min.	Тур.	Max.	Unit
off Charac	teristics	i						1	
D\/			/oltogo	$\frac{V_{GS} = 0 \text{ V, } I_D = 10 \text{ mA, } T_J = 25^{\circ}\text{C}}{V_{GS} = 0 \text{ V, } I_D = 10 \text{ mA, } T_J = 150^{\circ}\text{C}}$		600	-	-	- V
BV _{DSS}		Drain to Source Breakdown Voltage				650	-	-	
ΔΒV _{DSS} / ΔΤ _J	Breakdown Voltage Temperature Coefficient		ure	$I_D = 10 \text{ mA}$, Referenced to 25° C		-	0.67	-	V/ºC
I _{DSS} Zero G		Gate Voltage Drain Current		V _{DS} = 600 V, V _{GS} =		-	-	1	μA
000				V _{DS} = 480 V, V _{GS} =		-	2.5	-	
I _{GSS}	Gate to Body Leakage Current		nt	$V_{GS} = \pm 20 V, V_{DS} =$	0 V	-	-	±100	nA
On Charac	teristics								
V _{GS(th)}	Gate Th	reshold Voltage		$V_{GS} = V_{DS}, I_{D} = 250$) μΑ	2.5	-	3.5	V
R _{DS(on)}	Static Dr	ain to Source On Re	sistance	V _{GS} = 10 V, I _D = 14		-	112	130	mΩ
9 _{FS}	Forward	Transconductance		V _{DS} = 20 V, I _D = 14	A	-	26	-	S
Dynamic C	haracte	ristics							
C _{iss}	Input Ca	Capacitance				-	2700	3590	pF
C _{oss}	Output C	apacitance	·	— V _{DS} = 380 V, V _{GS} = 0 V, — f = 1 MHz		-	65	85	pF
C _{rss}	Reverse	Transfer Capacitanc	e			-	2.85	-	pF
C _{oss(eff.)}	Effective	Output Capacitance		V _{DS} = 0 V to 480 V,	V _{GS} = 0 V	-	240	-	pF
Q _{g(tot)}	Total Gat	te Charge at 10V		V _{DS} = 380 V, I _D = 14 A,		-	54	70	nC
Q _{gs}	Gate to S	Source Gate Charge		$V_{GS} = 10 V$		-	12	-	nC
Q _{gd}	Gate to I	Drain "Miller" Charge			(Note 4)	-	14	-	nC
ESR	Equivale	nt Series Resistance		f = 1 MHz		-	1	-	Ω
Switching	Charact	eristics							
t _{d(on)}		Delay Time					25	60	ns
t _r		Rise Time		V _{DD} = 380 V, I _D = 14 A,			16	42	ns
t _{d(off)}		Furn-Off Delay Time		$V_{GS} = 10 \text{ V}, \text{ R}_{g} = 4.7 \Omega$ (Note 4)		-	65	140	ns
t _f							4	18	ns
					. ,				
		e Characteristic							
I _S		n Continuous Drain to				-	-	28	A
I _{SM}	Maximum Pulsed Drain to Source Diode F					-	-	84	A
V _{SD}		Drain to Source Diode Forward Voltage		$V_{GS} = 0 V, I_{SD} = 14 A$		-	-	1.2	V
t _{rr}		erse Recovery Time erse Recovery Charge		V _{GS} = 0 V, I _{SD} = 14 A, dI _F /dt = 100 A/μs		-	376	-	ns
Q _{rr}	Reverse	Recovery Charge		$di_{\rm F}/dt = 100 A/\mu s$		-	7.6	-	μC
2. I _{AS} = 6 A, V _{DD} = 3. I _{SD} ≤ 14 A, di/dt	50 V, R _G = 25 ≤ 200 A/μs, V _I	inited by maximum junction 5 Ω , starting T _J = 25°C. _{DD} < BV _{DSS} , starting T _J = 25 rating temperature typical c	5°C.						

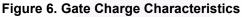


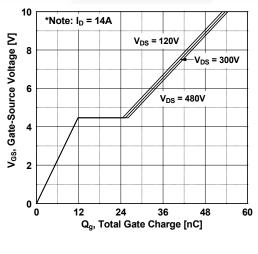




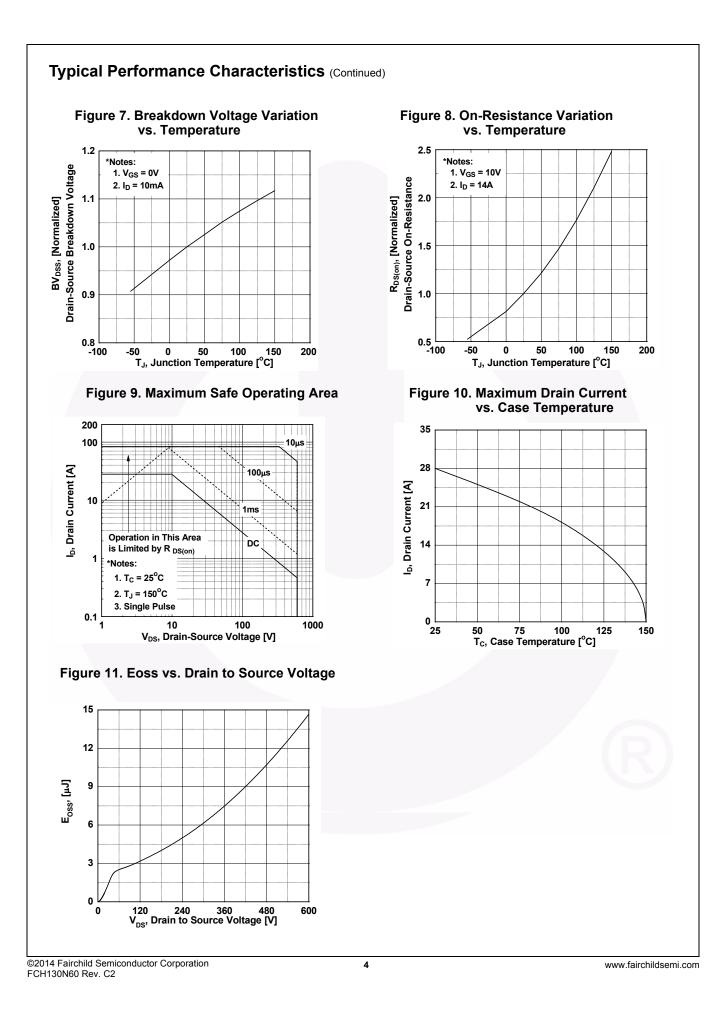
and Temperature

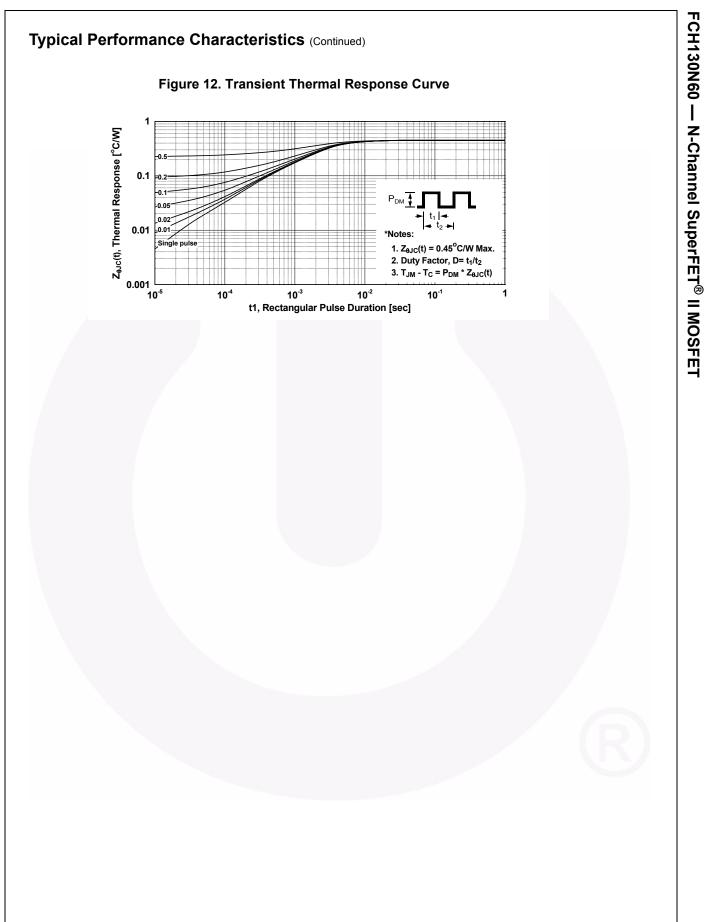


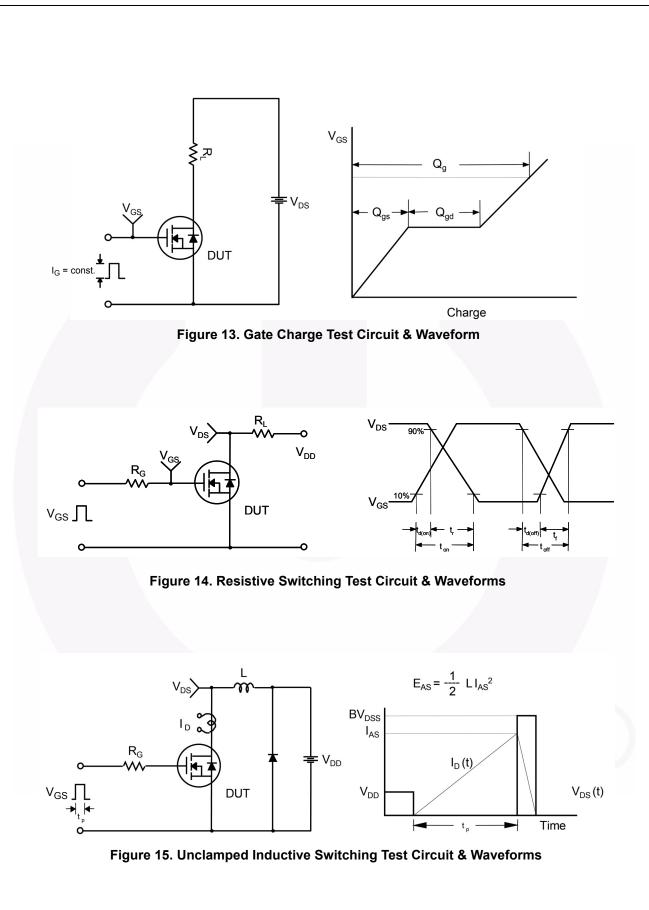




FCH130N60 — N-Channel SuperFET[®] II MOSFET

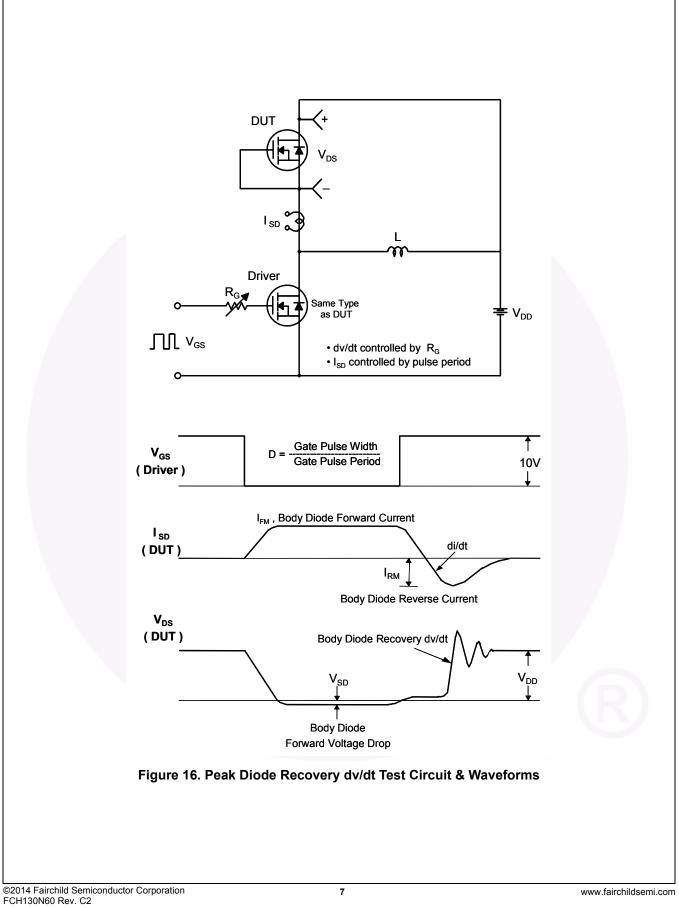


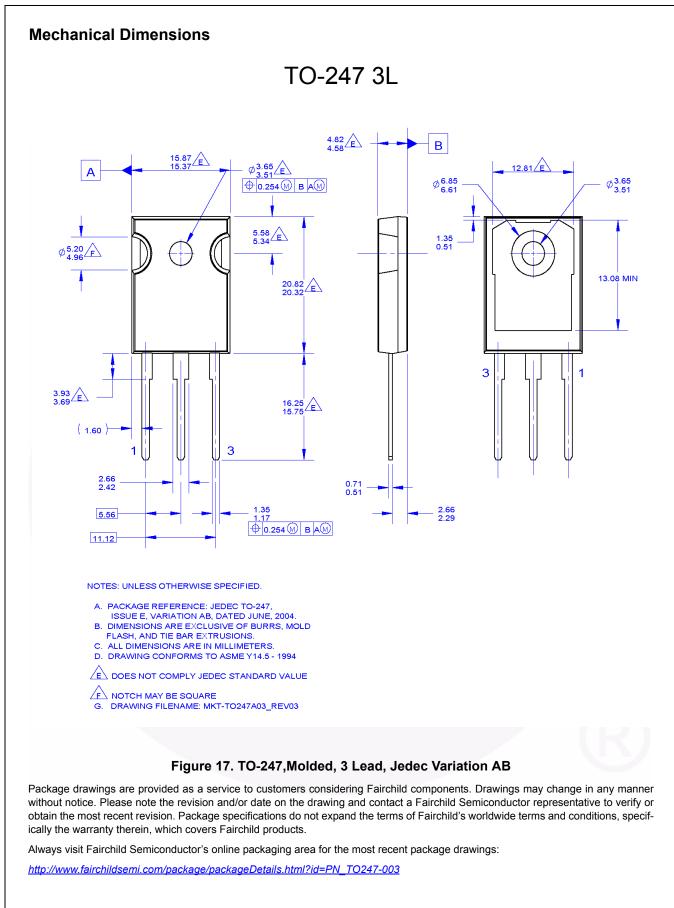




©2014 Fairchild Semiconductor Corporation FCH130N60 Rev. C2

FCH130N60 — N-Channel SuperFET[®] II MOSFET







TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ AX-CAP®* BitSiC™ Build it Now™ CorePOWER™ CROSSVOLT™ CTL™ CUrrent Transfer Logic™ DEUXPEED® Dual Cool™ EcoSPARK® EfficentMax™ ESBC™

Fairchild[®] Fairchild Semiconductor[®] FACT Quiet Series[™] FACT[®] FAST[®] FastvCore[™] FETBench[™] FPS[™] F-PFS™ FRFET® Global Power ResourceSM GreenBridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver® OptoHiT™ **OPTOLOGIC[®] OPTOPLANAR[®]**

()_® PowerTrench® PowerXS[™] Programmable Active Droop™ QFĔT QS™ Quiet Series™ RapidConfigure™ тм Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM[®] STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS[®] SyncFET™ Sync-Lock™

$$\label{eq:states} \begin{split} & \textbf{E}_{SYSTEM} \, \texttt{S}^* \\ & \textbf{TinyBoost}^{\textcircled{O}} \\ & \textbf{TinyBoost}^{\textcircled{O}} \\ & \textbf{TinyCalc}^{\textcircled{M}} \\ & \textbf{TinyLogic}^{\textcircled{M}} \\ & \textbf{TinyLogic}^{\textcircled{M}} \\ & \textbf{TinyPower}^{\textcircled{M}} \\ & \textbf{TinyPower}^{\textcircled{M}} \\ & \textbf{TinyPOWM}^{\textcircled{M}} \\ & \textbf{TinyPWM}^{\textcircled{M}} \\ & \textbf{TinyPWM}^{\textcircled{M}} \\ & \textbf{TinyPWM}^{\textcircled{M}} \\ & \textbf{TinyPWM}^{\textcircled{M}} \\ & \textbf{TinyPOWer}^{\textcircled{M}} \\ & \textbf{TinyPOwer}^$$

UHC[®] Ultra FRFET™ UniFET™ VCX™ VisualMax™ VoltagePlus™ XS™ ? ? ™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts buying direct or from authorized. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Product Status	Definition		
Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		
-	Formative / In Design First Production Full Production		

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly ori indirectly, any claim of personal injury or death

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: FCH130N60